8-bit Proprietary Microcontroller

CMOS

F²MC-8L MB89820 Series

MB89821/823/P825/PV820

DESCRIPTION

MB89820 series is a line of single-chip microcontrollers using the F²MC-8L* CPU core which can operate at low voltage but at high speed. In addition to an LCD controller/driver allowing 200-pixel display the microcontrollers contain a variety of peripheral functions such as timers, a UART, a serial interface, and an external interrupt. The configuration of the MB89820 series is therefore best suited to control of LCD display panels.

*: F²MC stands for FUJITSU Flexible Microcontroller.

FEATURES

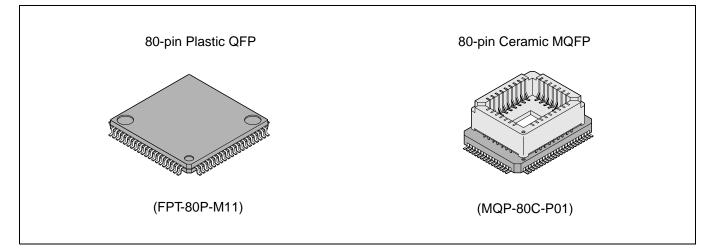
- Minimum execution time: $0.8 \,\mu\text{s}/5 \,\text{MHz} (\text{Vcc} = +5.0 \,\text{V})$
- F²MC-8L family CPU core

Instruction set optimized for controllers

 LCD controller/driver Max. 50 segments × 4 commons Divided resistor for LCD power supply Multiplication and division instructions 16-bit arithmetic operations Test and branch instructions Bit manipulation instructions, etc.

(Continued)

PACKAGES



(Continued)

- Three types of timers
 8-bit PWM timer (also usable as a reload timer)
 8-bit pulse width count timer (also usable as a reload timer)
 20-bit time-base timer
- Two serial interfaces
 8-bit synchronous serial interface (Switchable transfer direction allows communication with various equipment.)
 UART (5-, 7-, 8-bit transfer capable)
- External interrupt: 2 channels Capable of wake-up from low-power consumption modes (with an edge detection function)
- Low-power consumption modes
 Stop mode (Oscillation stops to minimize the current consumption.)
 Sleep mode (The CPU stops to reduce the current consumption to approx. 1/3 of normal.)

Part number Parameter	MB89821	MB89823	MB89P825	MB89PV820		
Classification	Mass produc (mask ROM		One-time PROM product	Piggyback/evaluation product for evaluation and development		
ROM size	4 K × 8 bits (internal mask ROM)	8 K × 8 bits (internal mask ROM)	16 K × 8 bits (internal PROM, programming with general-purpose EPROM programmer)	32 K × 8 bits (external ROM)		
RAM size	128×8 bits	256 >	× 8 bits	1024×8 bits		
CPU functions	Number of instr Instruction bit le Instruction leng Data bit length: Minimum execu Interrupt proces	ength: 8 th: 7 tion time: 0	136 8 bits 1 to 3 bytes 1, 8, 16 bits 0.8 μs/5 MHz (Vcc = 5.0 V) 7.2 μs/5 MHz (Vcc = 5.0 V)			
Ports	I/O ports (N-ch I/O ports (N-ch I/O ports (CMO Input ports: Total:	open-drain): 6 S): 6	 16 (All also serve as segment pins.)^{*1} 6 6 (5 ports also serve as peripheral I/O.) 4 (1 port also serves as an external interrupt input.) 32 (max.) 			
8-bit PWM timer	8-bit reload timer operation (toggled output capable) 8-bit resolution PWM operation Operating clock (pulse width count timer output: 0.8 μs, 12.8 μs, 51.2 μs/5 MHz)					
8-bit pulse width count timer	8-bit reload timer operation 8-bit pulse width count operation (continuous measurement capable "H" width, "L" width, or single-cycle measurement capable) Operating clock (0.8 μs, 3.2 μs, 25.6 μs/5 MHz)					
8-bit serial I/O	(one external shift clock	One clock selectable , three internal shift clock, th	bits from four transfer clocks pree internal shift clocks: 1.6 μ first selectability			

■ PRODUCT LINEUP

(Continued)

Part number Parameter	MB89821	MB89823	MB89P825	MB89PV820			
UART	Inte	5-, 7-, 8-bit transfer capable Internal baud-rate generator (max. 78125 bps/5 MHz)					
LCD controller/ driver	Common output: 4 Segment output: 50 (max.) Operating mode: 1/2 bias, 1/2 duty; 1/3 bias, 1/3 duty; 1/3 bias, 1/4 duty LCD display RAM size: 50×4 bits Dividing resistor for LCD driving: Built-in (An external resistor selectable)						
External interrupt	2 channels (edge selectable) (1 channel also serves as a pulse width count timer input)						
Standby mode	Sleep mode, stop mode						
Process	CMOS						
Operating voltage ^{*2}	2.2 V ^{*3} to 6.0 V 2.7 V to 6.0 V						
EPROM for use				MBM27C256A-20TV (LCC package)			

*1: The function is selected by the mask option.

*2: Varies with conditions such as the operating frequency. (See section "
Electrical Characteristics.")

*3: The operation at less than 2.2 V is assured separately. Please contact FUJITSU LIMITED.

■ PACKAGE AND CORRESPONDING PRODUCTS

Package	MB89821 MB89823 MB89P825	MB89PV820
FPT-80P-M11	0	×
MQP-80C-P01	×	0

 \bigcirc : Available \times : Not available

Note: For more information about each package, see section "
Package Dimensions."

■ DIFFERENCES AMONG PRODUCTS

1. Memory Size

Before evaluating using the piggyback product, verify its differences from the product that will actually be used. Take particular care on the following points:

- On the MB89821, the register bank address upper than 0140_H cannot be used. On the MB89823 and MB89P825, each register bank addresses upper than 0180_H can be used.
- On the MB89P825, addresses BFF0_H to BFF6_H comprise the option setting area, option settings can be read by reading these addresses.
- The stack area, etc., is set at the upper limit of the RAM.

2. Current Consumption

- In the case of the MB89PV820, add the current consumed by the EPROM which is connected to the top socket.
- However, the current consumption in sleep/stop modes is the same. (For more information, see section "
 Electrical Characteristics."

3. Mask Options

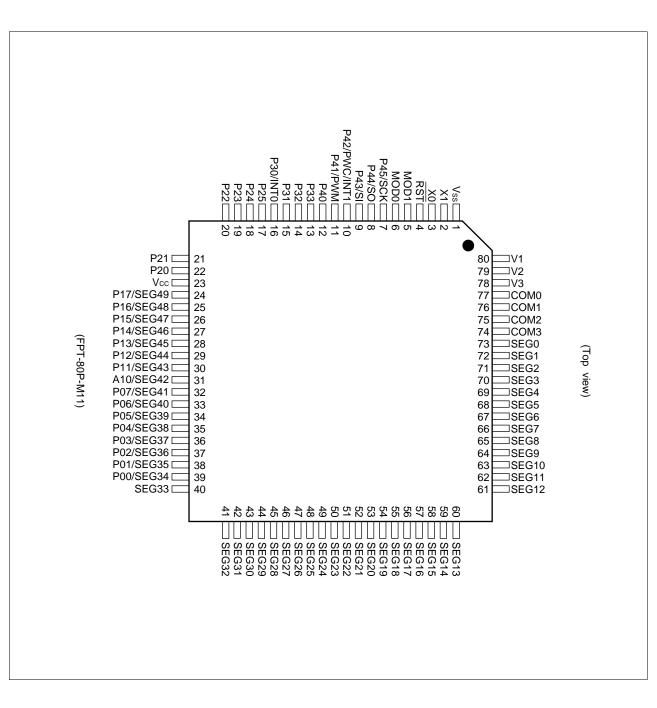
Functions that can be selected as options and how to designate these options vary by the product.

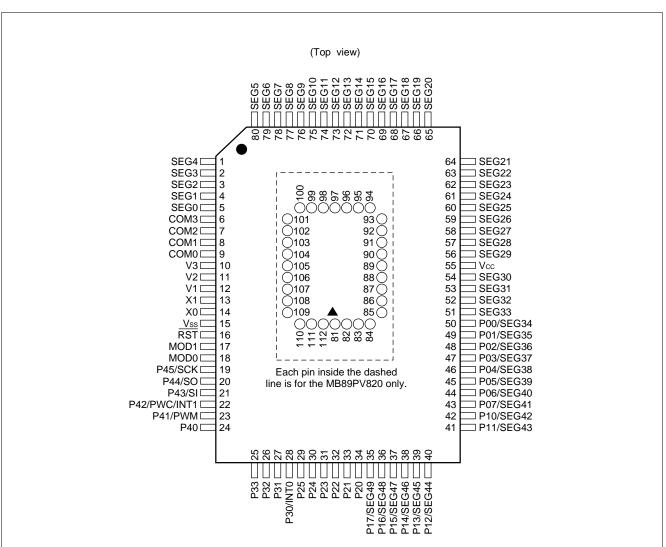
Before using options check section "
Mask Options."

Take particular care on the following point:

• Options are fixed on the MB89PV820.

PIN ASSIGNMENT





(MQP-80C-P01)

• Pin assignment on package top (MB89PV820 only)

Pin no.	Pin name						
81	N.C.	89	A2	97	N.C.	105	ŌĒ
82	Vpp	90	A1	98	O4	106	N.C.
83	A12	91	A0	99	O5	107	A11
84	A7	92	N.C.	100	O6	108	A9
85	A6	93	O1	101	07	109	A8
86	A5	94	O2	102	O8	110	A13
87	A4	95	O3	103	CE	111	A14
88	A3	96	Vss	104	A10	112	Vcc

■ PIN DESCRIPTION

Pin	no.		Circuit	
QFP ^{*1}	MQFP ^{*2}	Pin name	type	Function
3	14	X0	А	Clock crystal oscillator pins
2	13	X1	•	
6	18	MOD0	В	Operating mode selection pins
5	17	MOD1	*	Connect directly to Vss.
4	16	RST	С	Reset I/O pin This pin is an N-ch open-drain type with a pull-up resistor, and a hysteresis input type. "L" is output from this pin by an internal reset source (optional function). The internal circuit is initialized by the input of "L".
39 to 32	50 to 43	P00/SEG34 to P07/SEG41	D	General-purpose N-ch open-drain I/O ports Also serve as an LCD controller/driver segment output. The port and segment output are switched by mask option in 8-bit unit.
31 to 24	42 to 35	P10/SEG42 to P17/SEG49	D	General-purpose N-ch open-drain I/O ports Also serve as an LCD controller/driver segment output. The port and segment output are switched by mask option in 4 to 1-bit unit.
22 to 17	34 to 29	P20 to P25	F	General-purpose N-ch open-drain I/O ports A pull-up resistor option is provided.
16	28	P30/INT0	Н	General-purpose input port The input is hysteresis input. Also serves as an external interrupt input (INT0). A pull-up resistor option is provided.
15 to 13	27 to 25	P31 to P33	Н	General-purpose input ports These pins are a hysteresis input type. A pull-up resistor option is provided.
12	24	P40	E	General-purpose I/O port A pull-up resistor option is provided.
11	23	P41/PWM	E	General-purpose I/O port A pull-up resistor option is provided. Also serves as an 8-bit PWM timer toggle output (PWM).
10	22	P42/PWC/INT1	E	General-purpose I/O port A pull-up resistor option is provided. Also serves as an 8-bit pulse width count timer input (PWC) and an external interrupt input (INT1). The PWC and INT1 input is hysteresis input.
9	21	P43/SI	E	General-purpose I/O port A pull-up resistor option is provided. Also serves as an 8-bit serial I/O and a UART data input (SI). The SI input is hysteresis input.

*1: FPT-80P-M11

*2: MQP-80C-P01

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Pin no.		Pin name Circuit		Function		
QFP ^{*1}	MQFP ^{*2}	Fin name	type	Function		
8	20	P44/SO	E	General-purpose I/O port A pull-up resistor option is provided. Also serves as a serial I/O and a UART data output (SO).		
7	19	P45/SCK	E	General-purpose I/O port A pull-up resistor option is provided. Also serves as a serial I/O and a UART clock I/O (SCK). The SCK input is hysteresis input.		
73 to 40	5 to 1, 80 to 56, 54 to 51	SEG0 to SEG33	G	LCD controller/driver segment output pins		
77 to 74	9 to 6	COM0 to COM3	G	LCD controller/driver common output pins		
80 to 78	12 to 10	V1 to V3	—	LCD driving power supply pins		
23	55	Vcc	—	Power supply pin		
1	15	Vss	—	Power supply (GND) pin		

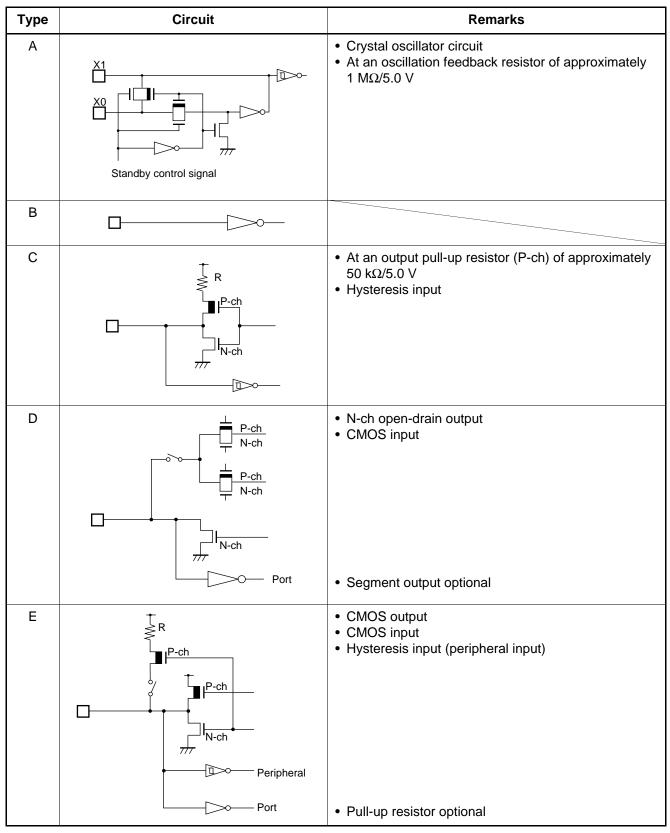
*1: FPT-80P-M11

*2: MQP-80C-P01

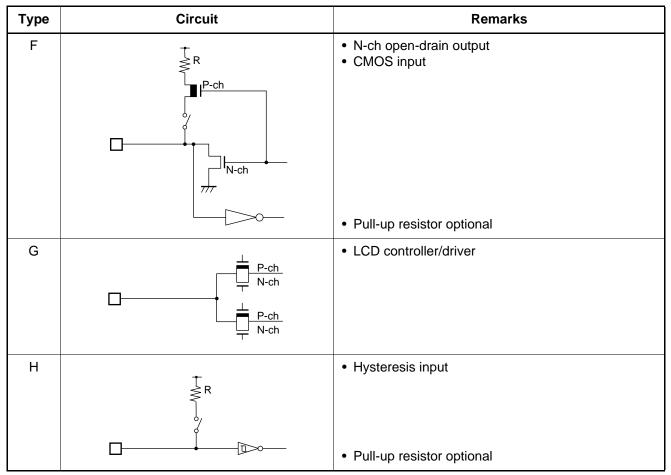
 External EPROM pins (MB89PV820 only) 	
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Pin no.	Pin name	I/O	Function
82	Vpp	0	"H" level output pin
83 84 85 86 87 88 89 90 91	A12 A7 A6 A5 A4 A3 A2 A1 A0	0	Address output pins
93 94 95	01 02 03	I	Data input pins
96	Vss	0	Power supply (GND) pin
98 99 100 101 102	O4 O5 O6 O7 O8	I	Data input pins
103	CE	0	ROM chip enable pin Outputs "H" during standby.
104	A10	0	Address output pin
105	ŌĒ	0	ROM output enable pin Outputs "L" at all times.
107 108 109	A11 A9 A8	0	Address output pins
110	A13	0	
111	A14	0	
112	Vcc	0	EPROM power supply pin
81 92 97 106	N.C.		Internally connected pins Be sure to leave them open.

■ I/O CIRCUIT TYPE







■ HANDLING DEVICES

1. Preventing Latchup

Latchup may occur on CMOS ICs if voltage higher than Vcc or lower than Vss is applied to input and output pins other than medium- to high-voltage pins or if higher than the voltage which shows on "1. Absolute Maximum Ratings" in section "■ Electrical Characteristics" is applied between Vcc and Vss.

When latchup occurs, power supply current increases rapidly and might thermally damage elements. When using, take great care not to exceed the absolute maximum ratings.

Also, take care to prevent the analog power supply (AVcc and AVR) and analog input from exceeding the digital power supply (Vcc) when the analog system power supply is turned on and off.

2. Treatment of Unused Input Pins

Leaving unused input pins open could cause malfunctions. They should be connected to a pull-up or pull-down resistor.

3. Treatment of Power Supply Pins on Microcontrollers with A/D and D/A Converters

Connect to be AVcc = DAVC = Vcc and AVss = AVR = Vss even if the A/D and D/A converters are not in use.

4. Treatment of N.C. Pins

Be sure to leave (internally connected) N.C. pins open.

5. Power Supply Voltage Fluctuations

Although V_{CC} power supply voltage is assured to operate within the rated range, a rapid fluctuation of the voltage could cause malfunctions, even if it occurs within the rated range. Stabilizing voltage supplied to the IC is therefore important. As stabilization guidelines, it is recommended to control power so that V_{CC} ripple fluctuations (P-P value) will be less than 10% of the standard V_{CC} value at the commercial frequency (50 to 60 Hz) and the transient fluctuation rate will be less than 0.1 V/ms at the time of a momentary fluctuation such as when power is switched.

6. Precautions when Using an External Clock

Even when an external clock is used, oscillation stabilization time is required for power-on reset (optional) and wake-up from stop mode.

■ PROGRAMMING TO THE EPROM ON THE MB89P825

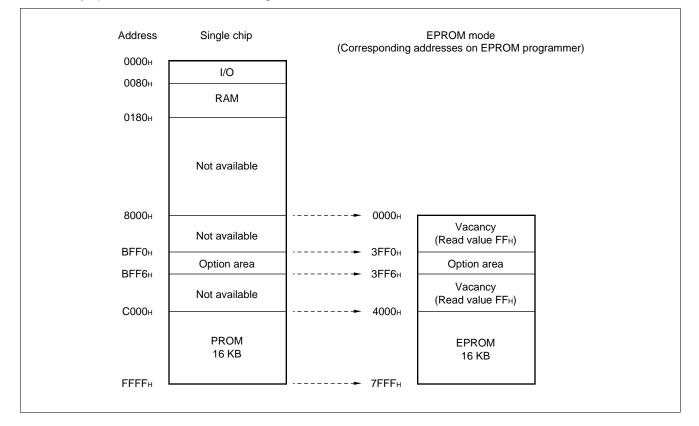
The MB89P825 is an OTPROM (one-time PROM) version for the MB89820 series.

1. Features

- 16-Kbyte PROM on chip
- Options can be set using the EPROM programmer.
- Equivalency to the MBM27C256A in EPROM mode (when programmed with the EPROM programmer)

2. Memory Space

Memory space in EPROM mode is diagrammed below.



3. Programming to the EPROM

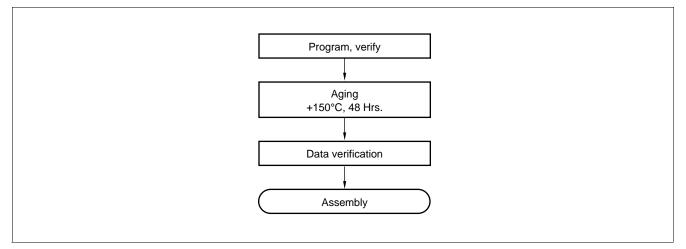
In EPROM mode, the MB89P825 functions equivalent to the MBM27C256A. This allows the PROM to be programmed with a general-purpose EPROM programmer (the electronic signature mode cannot be used) by using the dedicated socket adapter.

• Programming procedure

- (1) Set the EPROM programmer to the MBM27C256A.
- (2) Load program data into the EPROM programmer at 4000_H to 7FFF_H (note that addresses C000_H to FFFF_H while operating as a single chip assign to 4000_H to 7FFF_H in EPROM mode). Load option data into addresses 3FF0_H to 3FF5_H of the EPROM programmer. (For information about each corresponding option, see "7. OTPROM Option Bit Map."
- (3) Program with the EPROM programmer.

4. Recommended Screening Conditions

High-temperature aging is recommended as the pre-assembly screening procedure for a product for a product with a blanked OTPROM microcomputer program.



5. Programming Yield

All bits cannot be programmed at Fujitsu shipping test to a blanked OTPROM microcomputer, due to its nature. For this reason, a programming yield of 100% cannot be assured at all times.

6. EPROM Programmer Socket Adapter

Package	Compatible socket adapter
FPT-80P-M11	ROM-80QF2-28DP-8L3

Inquiry: Sun Hayato Co., Ltd.: TEL 81-3-3802-5760

7. OTPROM Option Bit Map

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
3FF0н	Vacancy Readable	Vacancy Readable	Vacancy Readable	Vacancy Readable	Vacancy Readable	Reset pin output 1: Yes 0: No	Oscillation stabilization time 1: 2 ¹⁷ /Fc 0: 2 ¹³ /Fc	Power-on reset 1: Yes 0: No
	Vacancy	Vacancy	Vacancy	Vacancy	Vacancy	Vacancy	Vacancy	Vacancy
3FF1⊦	Readable	Readable	Readable	Readable	Readable	Readable	Readable	Readable
	Vacancy	Vacancy	Vacancy	Vacancy	Vacancy	Vacancy	Vacancy	Vacancy
3FF2н	Readable	Readable	Readable	Readable	Readable	Readable	Readable	Readable
	Vacancy	Vacancy	P25 Pull-up	P24 Pull-up	P23 Pull-up	P22 Pull-up	P21 Pull-up	P20 Pull-up
3FF3⊦	Readable	Readable	1: No 0: Yes	1: No 0: Yes	1: No 0: Yes	1: No 0: Yes	1: No 0: Yes	1: No 0: Yes
	Vacancy	Vacancy	P45	P44	P43	P42	P41	P40
3FF4⊦	Readable	Readable	Pull-up 1: No 0: Yes	Pull-up 1: No 0: Yes	Pull-up 1: No 0: Yes	Pull-up 1: No 0: Yes	Pull-up 1: No 0: Yes	Pull-up 1: No 0: Yes
	Vacancy	Vacancy	Vacancy	Vacancy	P33 Pull-up	P32 Pull-up	P31 Pull-up	P30 Pull-up
3FF5н	Readable	Readable	Readable	Readable	1: No 0: Yes	1: No 0: Yes	1: No 0: Yes	1: No 0: Yes

Notes: • Set each bit to 1 to erase.

• Do not write 0 to the vacant bit.

The read value of the vacant bit is 1, unless 0 is written to it.

■ PROGRAMMING TO THE EPROM WITH PIGGYBACK/EVALUATION DEVICE

1. EPROM for Use

MBM27C256A-20TV

2. Programming Socket Adapter

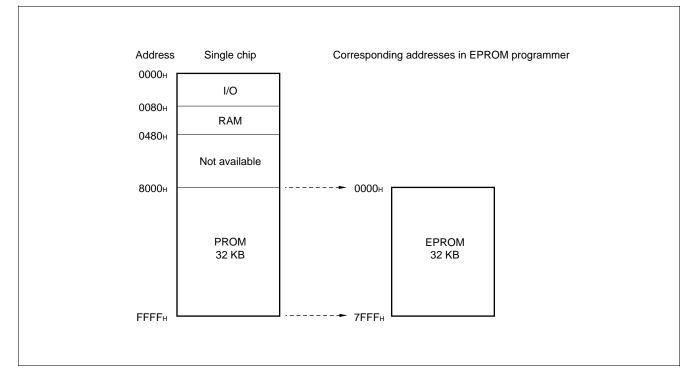
To program to the PROM using an EPROM programmer, use the socket adapter (manufacturer: Sun Hayato Co., Ltd.) listed below.

Package	Adapter socket part number
LCC-32 (Rectangle)	ROM-32LC-28DP-YG

Inquiry: Sun Hayato Co., Ltd.: TEL 81-3-3802-5760

3. Memory Space

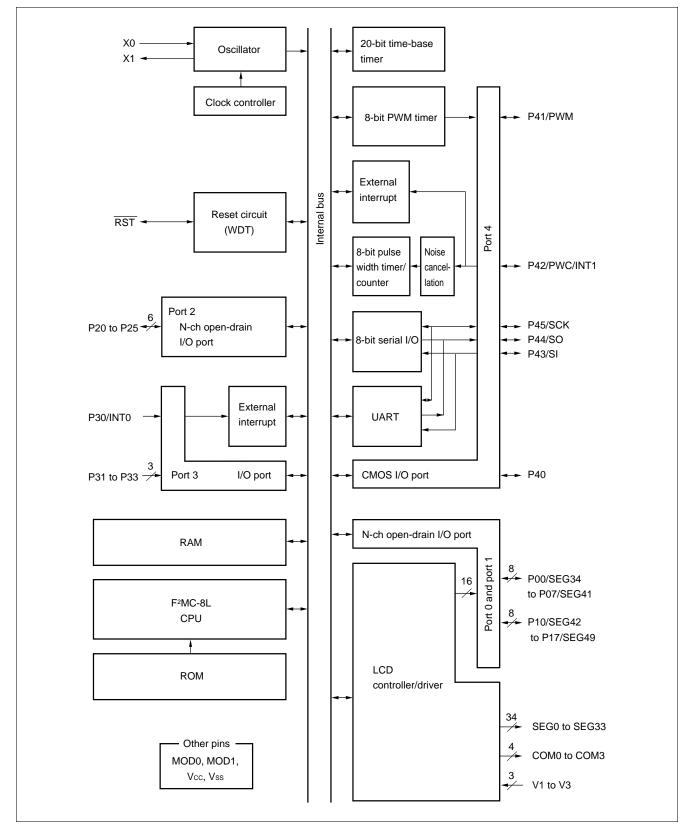
Memory space in each mode, such as 32 Kbyte PROM, option area is diagrammed below.



4. Programming to the EPROM

- (1) Set the EPROM programmer to the MBM27C256A.
- (2) Load program data into the EPROM programmer at 0000H to 7FFFH.
- (3) Program to 0000 to 7FFF_H with the EPROM programmer.

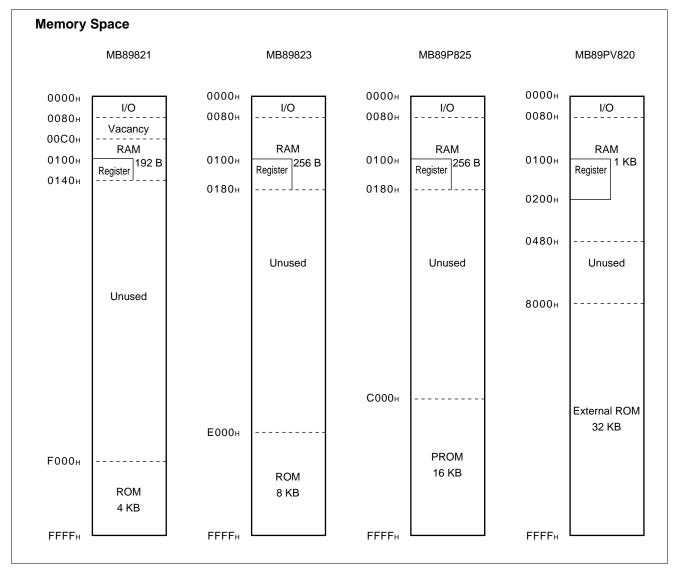
■ BLOCK DIAGRAM



■ CPU CORE

1. Memory Space

The microcontrollers of the MB89820 series offer a memory space of 64 Kbytes for storing all of I/O, data, and program areas. The I/O area is located at the lowest address. The data area is provided immediately above the I/O area. The data area can be divided into register, stack, and direct areas according to the application. The program area is located at exactly the opposite end, that is, near the highest address. Provide the tables of interrupt reset vectors and vector call instructions toward the highest address within the program area. The memory space of the MB89820 series is structured as illustrated below.



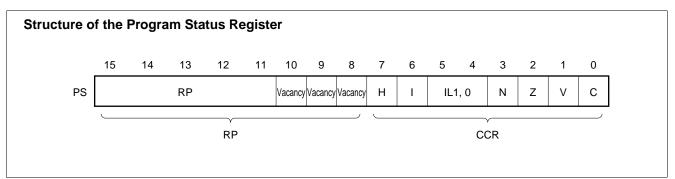
2. Registers

The F²MC-8L family has two types of registers; dedicated registers in the CPU and general-purpose registers in the memory. The following dedicated registers are provided:

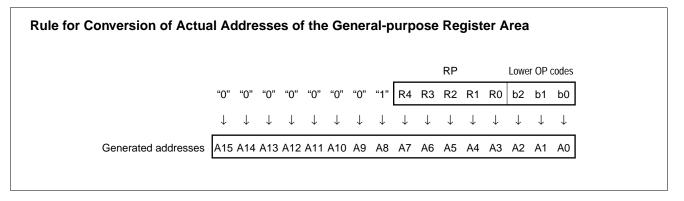
Program counter (PC):	A 16-bit register for indicating instruction storage positions
Accumulator (A):	A 16-bit temporary register for storing arithmetic operations, etc. When the instruction is an 8-bit data processing instruction, the lower byte is used.
Temporary accumulator (T):	A 16-bit register which performs arithmetic operations with the accumulator When the instruction is an 8-bit data processing instruction, the lower byte is used.
Index register (IX):	A 16-bit register for index modification
Extra pointer (EP):	A 16-bit pointer for indicating a memory address
Stack pointer (SP):	A 16-bit register for indicating a stack area
Program status (PS):	A 16-bit register for storing a register pointer, a condition code

◀ 16 bits	-	Initial value
PC	: Program counter	FFFDH
А	: Accumulator	Undefined
Т	: Temporary accumulator	Undefined
IX	: Index register	Undefined
EP	: Extra pointer	Undefined
SP	: Stack pointer	Undefined
PS		g = 0, IL1, IL0 = 11 er bits are undefined.

The PS can further be divided into higher 8 bits for use as a register bank pointer (RP) and the lower 8 bits for use as a condition code register (CCR). (See the diagram below.)



The RP indicates the address of the register bank currently in use. The relationship between the pointer contents and the actual address is based on the conversion rule illustrated below.



The CCR consists of bits indicating the results of arithmetic operations and the contents of transfer data and bits for control of CPU operations at the time of an interrupt.

- H-flag: Set when a carry or a borrow from bit 3 to bit 4 occurs as a result of an arithmetic operation. Cleared otherwise. This flag is for decimal adjustment instructions.
- I-flag: Interrupt is allowed when this flag is set to 1. Interrupt is prohibited when the flag is set to 0. Set to 0 when reset.
- IL1, 0: Indicates the level of the interrupt currently allowed. Processes an interrupt only if its request level is higher than the value indicated by this bit.

IL1	IL0	Interrupt level	High-low
0	0	1	High
0	1		t
1	0	2	
1	1	3	Low = no interrupt

- N-flag: Set if the MSB is set to 1 as the result of an arithmetic operation. Cleared when the bit is set to 0.
- Z-flag: Set when an arithmetic operation results in 0. Cleared otherwise.
- V-flag: Set if the complement on 2 overflows as a result of an arithmetic operation. Reset if the overflow does not occur.
- C-flag: Set when a carry or a borrow from bit 7 occurs as a result of an arithmetic operation. Cleared otherwise. Set to the shift-out value in the case of a shift instruction.

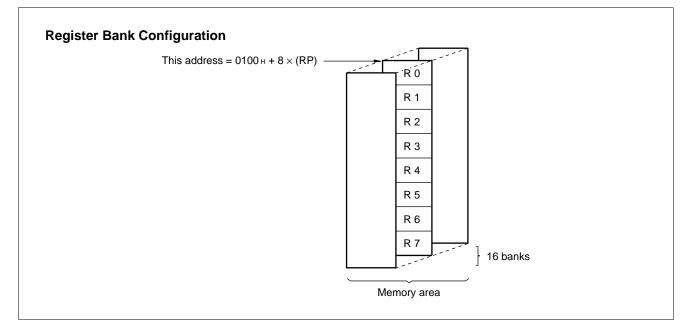
The following general-purpose registers are provided:

General-purpose registers: An 8-bit register for storing data

The general-purpose registers are 8 bits and located in the register banks of the memory. One bank contains eight registers and up to a total of 16 banks can be used on the MB89823 (RAM 256×8 bits). The bank currently in use is indicated by the register bank pointer (RP).

Note: The number of register banks that can be used varies with the RAM size.

MB89821	0100н to 013Fн	8 banks
MB89823	0100н to 017Fн	16 banks
MB89P825	0100н to 017Fн	16 banks
MB89PV820	0100н to 01FFн	32 banks



■ I/O MAP

Address	Read/write	Register name	Register description
00н	(R/W)	PDR0	Port 0 data register
01н		1	Vacancy
02н	(R/W)	PDR1	Port 1 data register
03н			Vacancy
04н	(R/W)	PDR2	Port 2 data register
05н			Vacancy
06н			Vacancy
07н			Vacancy
08н	(R/W)	STBC	Standby control register
09н	(R/W)	WDTC	Watchdog timer control register
0Ан	(R/W)	TBCR	Time-base timer control register
0Вн			Vacancy
0Сн	(R)	PDR3	Port 3 data register
0Dн		1	Vacancy
0Ен	(R/W)	PDR4	Port 4 data register
0Fн	(VV)	DDR4	Port 4 data direction register
10н			Vacancy
11н			Vacancy
12н	(R/W)	CNTR	PWM timer control register
13н	(W)	COMR	PWM timer compare register
14н	(R/W)	PCR1	PWC pulse width control register 1
15н	(R/W)	PCR2	PWC pulse width control register 2
16 _H	(R/W)	RLBR	PWC reload buffer register
17н	(R/W)	NCCR	PWC noise cancellation control register
1 8н		1	Vacancy
19н			Vacancy
1Ан			Vacancy
1Bн			Vacancy
1Сн	(R/W)	SMR	Serial mode register
1Dн	(R/W)	SDR	Serial data register
1Ен			Vacancy
1Fн			Vacancy

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Address	Read/write	Register name	Register description			
20н	(R/W)	SMC1	UART serial mode control register 1			
21н	(R/W)	SRC	UART serial rate control register			
22н	(R/W)	SSD	UART serial status/data register			
23н	(R/W)	SIDR/SODR	UART serial data register			
24н	(R/W)	SMC2	UART serial mode control register 2			
25н			Vacancy			
26н			Vacancy			
27н			Vacancy			
28н			Vacancy			
29н			Vacancy			
2Ан			Vacancy			
2Вн		Vacancy				
2Сн			Vacancy			
2Dн			Vacancy			
2Ен			Vacancy			
2 F н			Vacancy			
30н	(R/W)	EIC1	External interrupt 1 control register			
31н to 5Fн			Vacancy			
60н to 78н	(R/W)	VRAM	Display data RAM			
79 H	(R/W)	LCR1	LCD controller/driver control register			
7Ан	(R/W)	SEGR	Segment output selection register			
7Вн			Vacancy			
7Сн	(W)	ILR1	Interrupt level setting register 1			
7Dн	(W)	ILR2	Interrupt level setting register 2			
7 Ен	(W)	ILR3	Interrupt level setting register 3			
7 F н		1	Vacancy			

Note: Do not use vacancies.

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

(Vss = 0.0 V)

Barrantan	0	Va	lue	11	(V33 – 0.0 V)
Parameter	Symbol	Min.	Max.	Unit	Remarks
Power supply voltage	Vcc	Vss – 0.3	Vss + 7.0	V	
LCD power supply voltage	V3	Vss – 0.3	Vss + 7.0	V	V3 pin
	VI1	Vss - 0.3	Vcc + 0.3	V	V _{I1} must not exceed Vss + 7.0 V. Except P00 to P07 and P10 to P17 for the MB89P825/PV820, and P20 to P25 without a pull-up resistor
Input voltage	Vı2	Vss – 0.3	Vss + 7.0	V	P00 to P07 and P10 to P17 (when selected as ports) for the MB89821/ 823, and P20 to P25 without a pull- up resistor
	Vı3	Vss - 0.3	V3 + 0.3	V	P00 to P07 and P10 to P17 for the MB89P825/PV820
	Vo1	Vss - 0.3	Vcc + 0.3	V	V_{01} must not exceed V_{SS} + 7.0 V. Except P00 to P07 and P10 to P17 for the MB89P825/PV820, and P20 to P25 without a pull-up resistor
Output voltage	Vo2	Vss – 0.3	Vss + 7.0	V	P00 to P07 and P10 to P17 (when selected as ports) for the MB89821/ 823, and P20 to P25 without a pull- up resistor
	Vo3	Vss – 0.3	V3 + 0.3	V	P00 to P07 and P10 to P17 for the MB89P825/PV820
"L" level output current	lol	—	10	mA	Except power supply pins
"L" level average output current	Iolav	_	4	mA	Average value (operating current × operating rate) Except power supply pins
Total "L" level output current	ΣΙΟL	—	40	mA	
"H" level output current	Іон	—	-5	mA	Except power supply pins
"H" level average output current	Іонач	_	-2	mA	Average value (operating current × operating rate) Except power supply pins
Total "H" level output current	ΣІон	_	-10	mA	
Power consumption	PD	_	300	mW	
Operating temperature	TA	-40	+85	°C	
Storage temperature	Tstg	-55	+150	°C	

Precautions: Permanent device damage may occur if the above "Absolute Maximum Ratings" are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2. Recommended Operating Conditions

$(V_{SS} = 0.0 V)$									
Parameter	Symbol	Value		Unit	Remarks				
Farameter	Symbol	Min.	Max.		Remarks				
		2.2*	6.0*	V	Normal operation assurance range*				
Power supply voltage	Vcc	1.5	6.0	V	Retains the RAM state in stop mode				
LCD power supply voltage	V3	Vss	6.0	V	V3 pin LCD power supply range. The optimum value is dependent on the element in use.				
Operating temperature	TA	-40	+85	°C					

* : The minimum operating power supply voltage varies with the operating frequency.

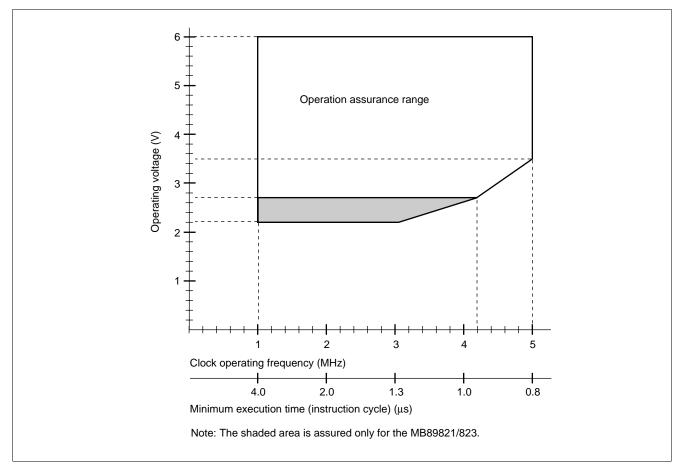


Figure 1 Operating Voltage vs. Clock Operating Frequency

Figure 1 indicates the operating frequency of the external oscillator at an instruction cycle of 4/Fc.

3. DC Characteristics

$(V_{CC} = V3 = +5.0 V, V_{S})$								$x = -40^{\circ}C \text{ to } +85^{\circ}C$
Parameter	Symbol	Pin	Condition		Value	lue		Remarks
i arameter	Symbol		Condition	Min.	Тур.	Max.	Unit	Renarks
"H" level input	Vін	P00 to P07, P10 to P17, P20 to P25, P30 to P33, P40 to P45	_	0.7 Vcc*1	_	Vcc + 0.3*1	v	
voltage	Vihs	RST, MOD0, MOD1, INT0, SCK, SI, PWC/INT1	_	0.8 Vcc	_	Vcc + 0.3	V	
"L" level input voltage	VIL	P00 to P07, P10 to P17, P22 to P25, P30 to P33, P40 to P45	_	Vcc - 0.3	_	0.3 Vcc*1	V	
Voltage	Vils	RST, MOD0, MOD1, INT0, SCK, SI, PWC/INT1	_	Vss-0.3	_	0.2 Vcc	V	
Open-drain output pin application voltage	VD	P20 to P25, P00 to P07, P10 to P17	_	Vss – 0.3		Vcc + 6.0	V	P00 to P07 and P10 to P17 (when selected as ports) for the MB89821/823, and P20 to P25 without pull-up resistor
"H" level output voltage	Vон	P40 to P45	Iон = -2 mA	2.4	—	_	V	
"L" level output voltage	Vol1	P00 to P07, P10 to P17, P20 to P25, P40 to P45	lo∟ = 1.8 mA		_	0.4	V	
	Vol2	RST	lo∟ = 4 mA	—		0.4	V	
		MOD0, MOD1, P30 to P33, P40 to P45			_	±5	μA	Without pull-up resistor for the MB89821/823
Input leakage current (Hi-z output leakage current)	IL11	MOD0, MOD1, P00 to P07, P10 to P17, P30 to P33, P40 to P45	0.0 V < Vı < Vcc	_	_	±5	μΑ	Without pull-up resistor for the MB89P825/PV820
		P00 to P07, P10 to P17, P20 to P25	0.0 V < Vı < 6.0 V	_		±1	μA	Without pull-up resistor for the MB89821/823
		P20 to P25		_		±1	μA	Without pull-up resistor for the MB89P825/PV820

 ΛI_{c} QE°C) 1/2 100C +

(Continued)

(Continued)

			(100 10	Value			,	
Parameter	Symbol	Pin	Condition	Min.	Тур.	Max.	Unit	Remarks
Pull-up resistance	Rpull	P20 to P25, P30 to P33, P40 to P45, RST	V1 = 0.0 V	25	50	100	kΩ	With pull-up resistor
Common output impedance	Rvсом	COM0 to COM3	V1 to V3 = +5.0 V	_	_	2.5	kΩ	
Segment output impedance	Rvseg	SEG0 to SEG49	V1 to V3 = +5.0 V	_	_	15	kΩ	
LCD divided resistance	RLCD	_	Between V3 and Vss	30	60	120	kΩ	
LCD leakage current	Ilcol	V1 to V3, COM0 to COM3, SEG0 to SEG49	_	_	_	±1	μA	
	Icc		Fc = 5 MHz t _{inst} *3 = 0.8 μs	_	3.5	5.0	mA	MB89821, MB89823, MB89PV820
				_	4.0	6.5	mA	MB89P825
Power supply current 2	Iccs	Vcc	$\begin{array}{l} F_{c}=5 \text{ MHz} \\ t_{inst}^{*3}=0.8 \ \mu s \\ Sleep \ mode \end{array}$	_	1.1	1.7	mA	MB89821, MB89823, MB89PV820, MB89P825
	leeu		T _A = +25°C	_	0.1	1	μA	MB89821, MB89823
	ICCH	Іссн	Stop mode	_	0.1	10	μA	MB89PV820, MB89P825
Input capacitance	CIN	Other than Vcc and Vss	f = 1 MHz	_	10	_	pF	

 $(V_{CC} = V3 = +5.0 \text{ V}, \text{ Vss} = 0.0 \text{ V}, \text{ T}_{A} = -40^{\circ}\text{C to } +85^{\circ}\text{C})$

*1: The input voltage to P00 to P07 and P10 to P17 for the MB89P825/PV820 must not exceed the LCD power supply voltage (V3 pin voltage).

*2: The measurement condition of power supply current is as follows: the external clock, open output pins and the external LCD dividing resistor. In the case of the MB89PV820, the current consumed by the connected EPROM and ICE is not included.

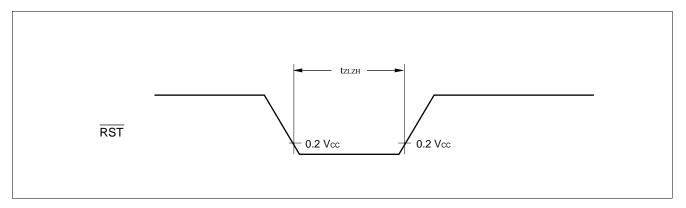
*3: For information on t_{inst}, see "(4) Instruction Cycle" in "4. AC Characteristics."

4. AC Characteristics

(1) Reset Timing

(Vcc = +5.0 V±10%, Vss = 0.0 V, T_A = -40°C to +85°C)

Parameter	Symbol	Condition		lue	Unit	Remarks
Faiameter	Symbol	Condition	Min.	Max.	Unit	itematks
RST "L" pulse width	t zlzh		48 t xcy∟		ns	

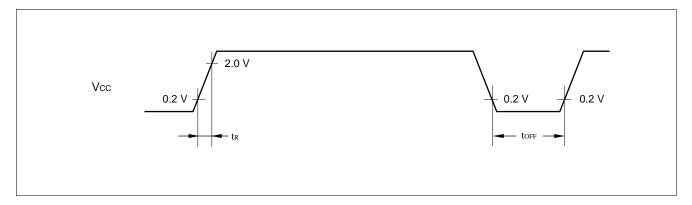


(2) Power-on Reset

 $(V_{SS} = 0.0 \text{ V}, \text{ } \text{T}_{A} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C})$

Parameter	Symbol C	Symbol Condition	Va	lue	Unit	Remarks
Faianetei	Symbol	Condition	Min.	Max.	Unit	
Power supply rising time	tR		_	50	ms	Power-on reset function only
Power supply cut-off time	toff	_	1		ms	Due to repeated operations

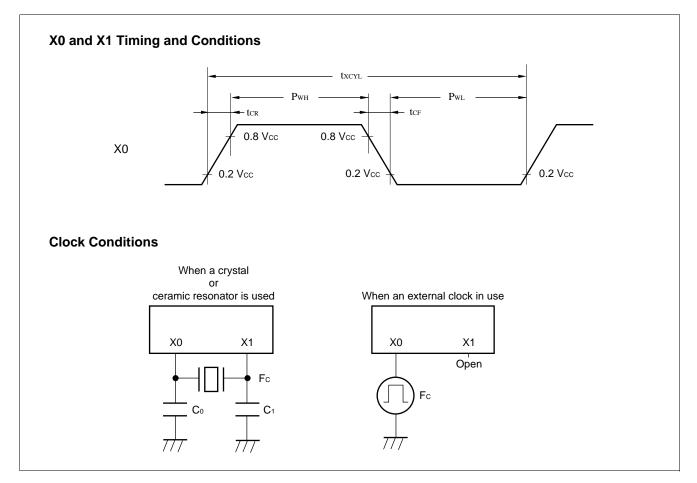
Note: Make sure that power supply rises within the selected oscillation stabilization time. If power supply voltage needs to be varied in the course of operation, a smooth voltage rise is recommended.



(3) Clock Timing

$(V_{SS} = 0.0 \text{ V}, \text{T}_{A} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$												
Parameter	Sym- bol	Pin	Condition	Value		Value		Value		Remarks		
Parameter	bol	ГШ	Condition	Min.	Тур.	Max.	Unit	Remarks				
Clock frequency	Fc			1	_	5	MHz					
Clock cycle time	t xcyL	X0, X1		200	_	1000	ns	Crystal or ceramic resonator				
Input clock duty ratio*	duty			30	—	70	%	External clock				
Input clock rising/ falling time	tcr tcf	X0				10	ns	External clock				

* : $duty = P_{WH}/t_{HCYL}$, P_{WL}/t_{HCYL}



(4) Instruction Cycle

Parameter	Symbol	Value (typical)	Unit	Remarks
Instruction cycle (minimum execution time)	tinst	4/Fc	μs	t_{inst} = 0.8 μs when operating at Fc = 5 MHz

(5) Serial I/O Timing

$(V_{CC} = +5.0 \text{ V} \pm 10\%, \text{ V}_{SS} = 0.0 \text{ V}, \text{ T}_{A} = -40^{\circ}\text{C}$										
Parameter	Symphol	Pin	Condition	Va	ue	Unit	Remarks			
Faidilielei	Symbol	ГШ	Condition	Min.	Max.	Unit	Remarks			
Serial clock cycle time	t scyc	SCK		2 tinst*	—	μs				
$SCK \downarrow \to SO$ time	t slov	SCK, SO	Internal shift clock	-200	200	ns				
Valid SI \rightarrow SCK \uparrow	tıvsн	SI, SCK	mode	0.5 tinst*	—	μs				
SCK $\uparrow \rightarrow$ valid SI hold time	tsнix	SCK, SI		0.5 tinst*	—	μs				
Serial clock "H" pulse width	t s∺s∟	SCK		1 tinst*	—	μs				
Serial clock "L" pulse width	t slsh	SCK	External	1 tinst*	—	μs				
$SCK \downarrow \to SO$ time	t slov	SCK, SO	shift clock	0	200	ns				
Valid SI \rightarrow SCK \uparrow	tıvsн	SI, SCK	mode	0.5 tinst*	—	μs				
SCK $\uparrow \rightarrow$ valid SI hold time	tsнıx	SCK, SI	1	0.5 t inst*		μs				

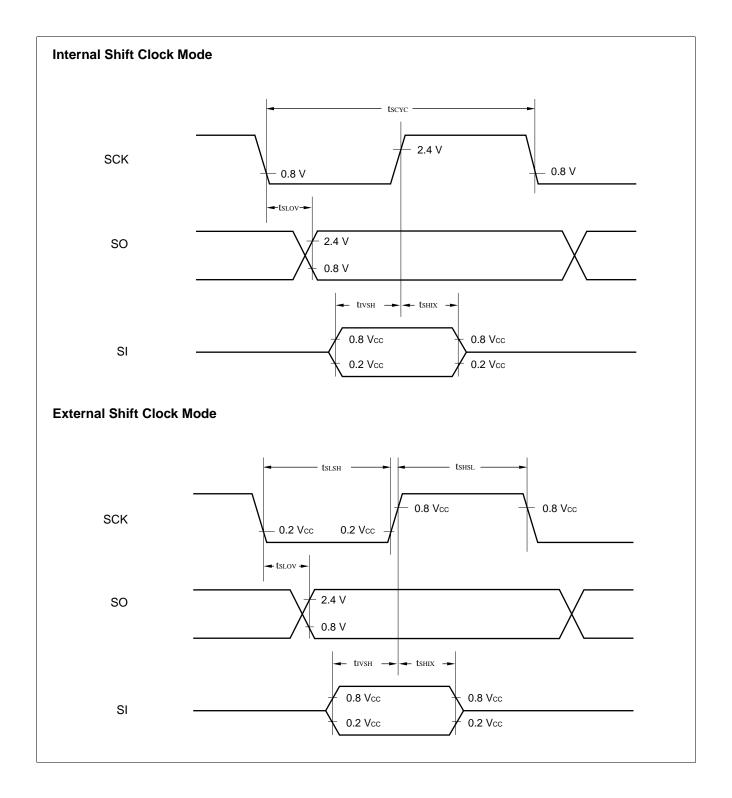
*: For information on tinst, see "(4) Instruction Cycle."

(6) UART Timing

Value Symbol Condition Parameter Pin Unit Remarks Min. Max. Serial clock cycle time SCK 2 tinst* ____ tscyc μs Internal $\mathsf{SCK} \downarrow \to \mathsf{SO}$ time SCK, SO -200 200 ns **t**slov shift clock Valid SI \rightarrow SCK \uparrow SI, SCK 0.5 tinst* ____ **t**ivsh mode μs SCK $\uparrow \rightarrow$ valid SI hold time SCK, SI 0.5 tinst* tsHIX μs ____ Serial clock "H" pulse width 1 tinst* **t**shsl ____ μs SCK Serial clock "L" pulse width 1 tinst* **t**slsh μs ____ External SCK $\downarrow \rightarrow$ SO time SCK, SO shift clock 0 200 ns tslov mode Valid SI \rightarrow SCK \uparrow SI, SCK 0.5 tinst* **t**ivsh ____ μs SCK $\uparrow \rightarrow$ valid SI hold time SCK, SI 0.5 tinst* **t**shix μs

* : For information on tinst, see "(4) Instruction Cycle."

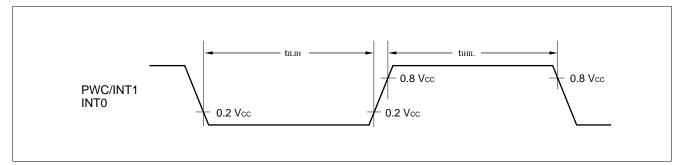
 $(V_{CC} = +5.0 \text{ V} \pm 10\%, \text{ Vss} = 0.0 \text{ V}, \text{ T}_{A} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C})$



(7) Peripheral Input Timing

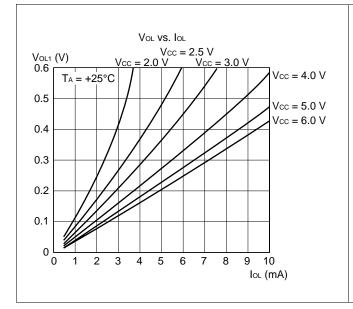
			(Vcc = +5.0)	V±10%, V	ss = 0.0 V	′, Ta = −4	40°C to +85°C
Parameter	Symbol	Pin	Condition	Va	lue	Unit	Remarks
			Condition	Min.	Max.		Remarks
Peripheral input "H" pulse width	tı∟ıн	PWC/INT1		2 tinst*	_	μs	
Peripheral input "L" pulse width	tını∟	INTO	_	2 t _{inst} *		μs	

* : For information on tinst, see "(4) Instruction Cycle."

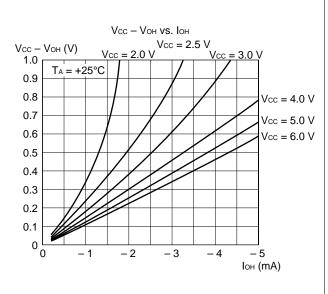


■ EXAMPLE CHARACTERISTICS

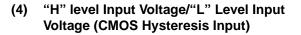
(1) "L" Level Output Voltage

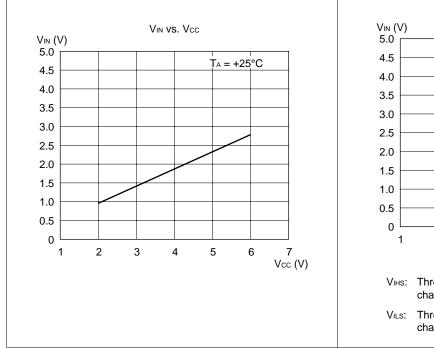


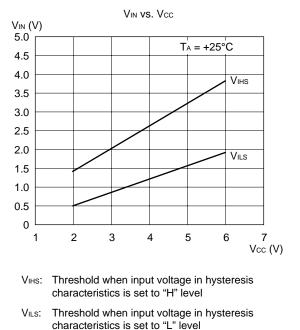
(2) "H" Level Output Voltage

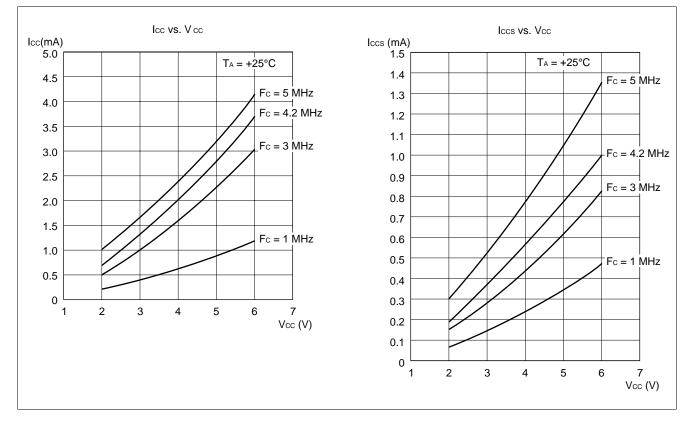


(3) "H" Level Input Voltage/"L" Level Input Voltage (CMOS Input)



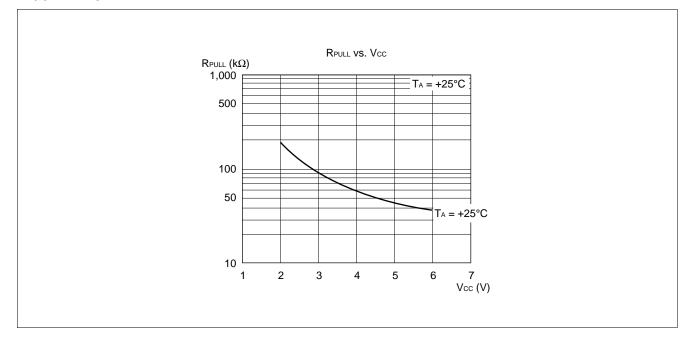






(5) Power Supply Current (External Clock)

(6) Pull-up Resistance



■ INSTRUCTIONS

Execution instructions can be divided into the following four groups:

- Transfer
- Arithmetic operation
- Branch
- Others

Table 1 lists symbols used for notation of instructions.

Symbol	Meaning
dir	Direct address (8 bits)
off	Offset (8 bits)
ext	Extended address (16 bits)
#vct	Vector table number (3 bits)
#d8	Immediate data (8 bits)
#d16	Immediate data (16 bits)
dir: b	Bit direct address (8:3 bits)
rel	Branch relative address (8 bits)
@	Register indirect (Example: @A, @IX, @EP)
A	Accumulator A (Whether its length is 8 or 16 bits is determined by the instruction in use.)
AH	Upper 8 bits of accumulator A (8 bits)
AL	Lower 8 bits of accumulator A (8 bits)
т	Temporary accumulator T (Whether its length is 8 or 16 bits is determined by the instruction in use.)
TH	Upper 8 bits of temporary accumulator T (8 bits)
TL	Lower 8 bits of temporary accumulator T (8 bits)
IX	Index register IX (16 bits)

Table 1 Instruction Symbols

(Continued)

(Continued)

Symbol	Meaning
EP	Extra pointer EP (16 bits)
PC	Program counter PC (16 bits)
SP	Stack pointer SP (16 bits)
PS	Program status PS (16 bits)
dr	Accumulator A or index register IX (16 bits)
CCR	Condition code register CCR (8 bits)
RP	Register bank pointer RP (5 bits)
Ri	General-purpose register Ri (8 bits, i = 0 to 7)
×	Indicates that the very \times is the immediate data. (Whether its length is 8 or 16 bits is determined by the instruction in use.)
(×)	Indicates that the contents of \times is the target of accessing. (Whether its length is 8 or 16 bits is determined by the instruction in use.)
((×))	The address indicated by the contents of \times is the target of accessing. (Whether its length is 8 or 16 bits is determined by the instruction in use.)

Columns indicate the following:

Mnemonic:	Assembler notation of an instruction
~:	Number of instructions
#:	Number of bytes
Operation:	Operation of an instruction
TL, TH, AH:	A content change when each of the TL, TH, and AH instructions is executed. Symbols in the column indicate the following:
	 "-" indicates no change. dH is the 8 upper bits of operation description data. AL and AH must become the contents of AL and AH immediately before the instruction is executed. 00 becomes 00.
N, Z, V, C:	An instruction of which the corresponding flag will change. If + is written in this column, the relevant instruction will change its corresponding flag.
OP code:	Code of an instruction. If an instruction is more than one code, it is written according to the following rule: Example: 48 to $4F \leftarrow$ This indicates 48, 49, 4F.

Mnemonic	~	#	Operation	TL	TH	AH	NZVC	OP code
MOV dir,A	3	2	$(dir) \leftarrow (A)$	-	_	-		45
MOV @IX +off,A	4	2	$((IX) + off) \leftarrow (A)$	_	-	-		46
MOV ext,A	4	3	$(ext) \leftarrow (A)$	_	-	-		61
MOV @EP,A	3	1	((EP)) ← (A)	_	-	-		47
MOV Ri,A	3	1	$(Ri) \leftarrow (A)$	_	_	_		48 to 4F
MOV A,#d8	2	2	$(A)' \leftarrow dB'$	AL	_	_	+ +	04
MOV A,dir	3	2	$(A) \leftarrow (dir)$	AL	_	_	+ +	05
MOV A,@IX +off	4	2	$(A) \leftarrow ((IX) + off)$	AL	_	_	++	06
MOV A,ext	4	3	$(A) \leftarrow (ext)$	AL	_	_	++	60
MOV A,@A	3	1	$(A) \leftarrow ((A))$	AL	_	_	++	92
MOV A,@EP	3	1	$(A) \leftarrow ((EP))$	AL	_	_	++	07
MOV A,Ri	3	1	$(A) \leftarrow (Ri)$	AL	_	_	++	08 to 0F
MOV dir,#d8	4	3	$(dir) \leftarrow d8$	_	_	_		85
MOV @IX +off,#d8	5	3	$((IX) + off) \leftarrow d8$	_	_	_		86
MOV @EP,#d8	4	2	$((EP)) \leftarrow d8$	_	_	_		87
MOV @LI,#d0 MOV Ri,#d8	4	2	((L1)) ← d8	_		_		88 to 8F
MOVW dir,A	4	2		_	_			00 10 0F D5
	5	2	$(dir) \leftarrow (AH), (dir + 1) \leftarrow (AL)$	-	_			D5 D6
MOVW @IX +off,A	Э	2	$((IX) + off) \leftarrow (AH),$	-	-	-		Do
	-	~	$((IX) + off + 1) \leftarrow (AL)$					D 4
MOVW ext,A	5	3	$(\text{ext}) \leftarrow (\text{AH}), (\text{ext} + 1) \leftarrow (\text{AL})$	-	-	-		D4
MOVW @EP,A	4	1	$((EP)) \leftarrow (AH), ((EP) + 1) \leftarrow (AL)$	-	-	-		D7
MOVW EP,A	2	1	$(EP) \leftarrow (A)$	_		<u> </u>		E3
MOVW A,#d16	3	3	(A) ← d16	AL	AH	dH	++	E4
MOVW A,dir	4	2	$(AH) \leftarrow (dir), (AL) \leftarrow (dir + 1)$	AL	AH	dH	++	C5
MOVW A,@IX +off	5	2	$(AH) \leftarrow ((IX) + off),$	AL	AH	dH	++	C6
	_		$(AL) \leftarrow ((IX) + off + 1)$.
MOVW A,ext	5	3	$(AH) \leftarrow (ext), (AL) \leftarrow (ext + 1)$	AL	AH	dH	++	C4
MOVW A,@A	4	1	$(AH) \leftarrow ((A)), (AL) \leftarrow ((A)) + 1)$	AL	AH	dH	++	93
MOVW A,@EP	4	1	$(AH) \leftarrow ((EP)), (AL) \leftarrow ((EP) + 1)$	AL	AH	dH	++	C7
MOVW A,EP	2	1	$(A) \leftarrow (EP)$	-	-	dH		F3
MOVW EP,#d16	3	3	(EP) ← d16	-	-	-		E7
MOVW IX,A	2	1	$(IX) \leftarrow (A)$	-	-	_		E2
MOVW A,IX	2	1	$(A) \leftarrow (IX)$	-	-	dH		F2
MOVW SP,A	2	1	$(SP) \leftarrow (A)$	-	-	-		E1
MOVW A,SP	2	1	$(A) \leftarrow (SP)$	-	-	dH		F1
MOV @A,T	3	1	$((A)) \leftarrow (T)$	-	-	-		82
MOVW @A,T	4	1	$(\text{ (A) }) \leftarrow (\text{TH}), (\text{ (A) } + 1) \leftarrow (\text{TL})$	_	-	-		83
MOVW IX,#d16	3	3	$(IX) \leftarrow d16$	-	-	-		E6
MOVW A,PS	2	1	$(A) \leftarrow (PS)$	-	-	dH		70
MOVW PS,A	2	1	$(PS) \leftarrow (A)$	-	-	-	++++	71
MOVW SP,#d16	3	3	(SP) ← d16	_	-	-		E5
SWAP	2	1	$(AH) \leftrightarrow (AL)$	_	-	AL		10
SETB dir: b	4	2	(dir): b ← 1	_	-	-		A8 to AF
CLRB dir: b	4	2	(dir): b ← 0	—	-	-		A0 to A7
XCH A,T	2	1	(AL)́ ↔ (TL)	AL	_	_		42
XCHW A,T	3	1	$(A) \leftrightarrow (T)$	AL	AH	dH		43
XCHW A,EP	3	1	$(A) \leftrightarrow (EP)$	_	_	dH		F7
XCHW A,IX	3	1	$(A) \leftrightarrow (IX)$	_	_	dH		F6
XCHW A,SP	3	1	$(A) \leftrightarrow (SP)$	_	_	dH		F5
MOVW A,PC	2	1	$(A) \leftarrow (PC)$	_	_	dH		F0
	-	•	···· ·· ··					

 Table 2
 Transfer Instructions (48 instructions)

Notes: \bullet During byte transfer to A, T \leftarrow A is restricted to low bytes.

 Operands in more than one operand instruction must be stored in the order in which their mnemonics are written. (Reverse arrangement of F²MC-8 family)

Mnemonic	~	#	Operation	TL	тн	AH	NZVC	OP code
ADDC A,Ri	3	1	$(A) \leftarrow (A) + (Ri) + C$	-	_	_	++++	28 to 2F
ADDC A,#d8	2	2	$(A) \leftarrow (A) + d8 + C$	—	—	—	+ + + +	24
ADDC A,dir	3	2	$(A) \leftarrow (A) + (dir) + C$	-	—	—	++++	25
ADDC A,@IX +off	4	2	$(A) \leftarrow (A) + ((IX) + off) + C$	—	—	—	++++	26
ADDC A,@EP	3	1	$(A) \leftarrow (A) + ((EP)) + C$	-	_	—	++++	27
ADDCW A	3	1	$(A) \leftarrow (A) + (T) + C$	-	_	dH	+ + + +	23
	2	1	$(AL) \leftarrow (AL) + (TL) + C$	-	-	-	++++	22 20 to 25
SUBC A,Ri	3	1	$(A) \leftarrow (A) - (Ri) - C$	_	—	-	++++	38 to 3F
SUBC A,#d8	2 3	2	$(A) \leftarrow (A) - d8 - C$	-	—	—	++++	34
SUBC A,dir	3 4	2 2	$(A) \leftarrow (A) - (dir) - C$	-	-	-	++++	35 36
SUBC A,@IX +off	4	2	$(A) \leftarrow (A) - ((IX) + off) - C$	_	_	_	++++	36 37
SUBC A,@EP SUBCW A	3 3	1	$(A) \leftarrow (A) - ((EP)) - C$	_	_	dH	++++	37
SUBC A	2	1	$(A) \leftarrow (T) - (A) - C$ $(AL) \leftarrow (TL) - (AL) - C$		_		++++	33
INC Ri	4	1	$(\text{Ri}) \leftarrow (\text{Ri}) + 1$				+++-	C8 to CF
INC IN INCW EP	3	1	$(EP) \leftarrow (EP) + 1$		_	_	+++-	C8 10 C1
INCW IX	3	1	$(Lr) \leftarrow (Lr) + 1$ $(IX) \leftarrow (IX) + 1$		_			C2
INCW A	3	1	$(A) \leftarrow (A) + 1$	_	_	dH	++	C0
DEC Ri	4	1	$(A) \leftarrow (A) + 1$ $(Ri) \leftarrow (Ri) - 1$	_	_	_	+++-	D8 toDF
DECW EP	3	1	$(EP) \leftarrow (EP) - 1$	_	_	_		D3
DECW IX	3	1	$(IX) \leftarrow (IX) - 1$	_	_	_		D2
DECW A	3	1	$(A) \leftarrow (A) - 1$	_	_	dH	++	D0
MULU A	19	1	$(A) \leftarrow (AL) \times (TL)$	_	_	dH		01
DIVU A	21	1	$(A) \leftarrow (T) / (AL), MOD \rightarrow (T)$	dL	00	00		11
ANDW A	3	1	$(A) \leftarrow (A) \land (T)$	_	_	dH	+ + R –	63
ORW A	3	1	$(A) \leftarrow (A) \lor (A)$	_	_	dH	+ + R –	73
XORW A	3	1	$(A) \leftarrow (A) \forall (A) \rightarrow (A)$	_	_	dH	+ + R –	53
CMP A	2	1	(TL) – (ÁL)	_	_	_	+ + + +	12
CMPW A	3	1	(T) - (A)	_	_	_	+ + + +	13
RORC A	2	1	$ ightarrow C \rightarrow A \neg$	_	—	—	+ + - +	03
ROLC A	2	1		_	_	_	++-+	02
1102071	-							02
CMP A,#d8	2	2	(A) – d8	_	_	_	+ + + +	14
CMP A,dir	3	2 2	(A) - (dir)	_	_	_	+ + + +	15
CMP A,@EP	3	1	(A) – ((EP))	—	—	—	+ + + +	17
CMP A,@IX +off	4	2	(A) – ((IX) +off)	-	—	—	+ + + +	16
CMP A,Ri	3	1	(A) – (Ri)	-	—	—	+ + + +	18 to 1F
DAA	2	1	Decimal adjust for addition	-	—	—	+ + + +	84
DAS	2	1	Decimal adjust for subtraction	—	—	—	+ + + +	94
XOR A	2	1	$(A) \leftarrow (AL) \forall (TL)$	—	—	—	+ + R –	52
XOR A,#d8	2	2	$(A) \leftarrow (AL) \forall d8$	-	-	-	+ + R –	54
XOR A,dir	3	2	$(A) \leftarrow (AL) \forall (dir)$	-	-	-	+ + R –	55
XOR A,@EP	3	1	$(A) \leftarrow (AL) \forall ((EP))$	—	—	-	+ + R –	57
XOR A,@IX +off	4	2	$(A) \leftarrow (AL) \forall ((IX) + off)$	—	-	-	+ + R –	56
XOR A,Ri	3	1	$(A) \leftarrow (AL) \forall (Ri)$	-	—	—	+ + R –	58 to 5F
	2	1	$(A) \leftarrow (AL) \land (TL)$	-	-	-	++R-	62
AND A,#d8	2	2	$(A) \leftarrow (AL) \land d8$	—	-	-	++R-	64 65
AND A,dir	3	2	$(A) \leftarrow (AL) \land (dir)$	-	-	-	+ + R –	65

 Table 3
 Arithmetic Operation Instructions (62 instructions)

(Continued)

(Continued)

Mnemonic	~	#	Operation	TL	ΤН	AH	NZVC	OP code
AND A,@EP	3	1	$(A) \leftarrow (AL) \land ((EP))$	-	_	_	+ + R –	67
AND A,@IX +off	4	2	$(A) \leftarrow (AL) \land ((IX) + off)$	-	_	_	+ + R –	66
AND A,Ri	3	1	$(A) \leftarrow (AL) \land (Ri)$	_	_	_	+ + R –	68 to 6F
OR A	2	1	$(A) \leftarrow (AL) \lor (TL)$	_	_	_	+ + R –	72
OR A,#d8	2	2	$(A) \leftarrow (AL) \lor d8$	-	_	_	+ + R –	74
OR A,dir	3	2	$(A) \leftarrow (AL) \lor (dir)$	-	_	_	+ + R –	75
OR A,@EP	3	1	$(A) \leftarrow (AL) \lor ((EP))$	-	_	_	+ + R –	77
OR A,@IX +off	4	2	$(A) \leftarrow (AL) \lor ((IX) + off)$	-	_	_	+ + R –	76
OR A,Ri	3	1	$(A) \leftarrow (AL) \lor (Ri)$	-	_	_	+ + R –	78 to 7F
CMP dir,#d8	5	3	(dir) – d8	-	_	_	+ + + +	95
CMP @EP,#d8	4	2	((ÉP)) – d8	-	_	_	+ + + +	97
CMP @IX +off,#d8	5	3	((IX) +off) – d8	-	_	_	+ + + +	96
CMP Ri,#d8	4	2	(Ri) – d8	-	_	_	+ + + +	98 to 9F
INCW SP	3	1	(SP) ← (ŚP) + 1	-	—	—		C1
DECW SP	3	1	(SP) ← (SP) − 1	-	—	-		D1

Mnemonic	~	#	Operation	TL	TH	AH	NZVC	OP code
BZ/BEQ rel	3	2	If Z = 1 then PC \leftarrow PC + rel	_	_	_		FD
BNZ/BNE rel	3	2	If $Z = 0$ then PC \leftarrow PC + rel	_	_	_		FC
BC/BLO rel	3	2	If C = 1 then PC \leftarrow PC + rel	_	_	_		F9
BNC/BHS rel	3	2	If C = 0 then PC \leftarrow PC + rel	_	_	_		F8
BN rel	3	2	If N = 1 then PC \leftarrow PC + rel	_	_	_		FB
BP rel	3	2	If N = 0 then PC \leftarrow PC + rel	_	_	_		FA
BLT rel	3	2	If V \forall N = 1 then PC \leftarrow PC + rel	_	_	_		FF
BGE rel	3	2	If V \forall N = 0 then PC \leftarrow PC + rel	_	_	_		FE
BBC dir: b,rel	5	3	If (dir: b) = 0 then PC \leftarrow PC + rel	_	_	_	-+	B0 to B7
BBS dir: b,rel	5	3	If (dir: b) = 1 then $PC \leftarrow PC + rel$	_	_	_	-+	B8 to BF
JMP @A	2	1	$(PC) \leftarrow (A)$	_	_	_		E0
JMP ext	3	3	$(PC) \leftarrow ext$	_	_	_		21
CALLV #vct	6	1	Vector call	_	_	_		E8 to EF
CALL ext	6	3	Subroutine call	_	_	_		31
XCHW A,PC	3	1	$(PC) \leftarrow (A), (A) \leftarrow (PC) + 1$	_	_	dH		F4
RET	4	1	Return from subrountine	—	_	_		20
RETI	6	1	Return form interrupt	-	-	-	Restore	30

Table 5	Other Instructions	(9 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	NZVC	OP code
PUSHW A	4	1		-	_	_		40
POPW A	4	1		-	-	dH		50
PUSHW IX	4	1		-	-	_		41
POPW IX	4	1		-	-	—		51
NOP	1	1		-	-	_		00
CLRC	1	1		-	-	—	R	81
SETC	1	1		-	-	—	S	91
CLRI	1	1		-	-	—		80
SETI	1	1		—	—	-		90

■ INSTRUCTION MAP

ГН	0	٢	2	3	4	5	9	7	8	6	А	В	ပ	۵	ш	ш
0	NOP	SWAP	RET	RETI	A A	POPW A	MOV A,ext	NVOM A,PS	CLRI	SETI	CLRB dir: 0	BBC dir: 0,rel	INCW A	A DECW	∀@ dMſ	MOVW A,PC
٢	MULU A	DIVU A	JMP addr16	CALL addr16	XI MHSNd	NHOPW XI	MOV ext,A	MOVW PS,A	CLRC	SETC	CLRB dir: 1	BBC dir: 1,rel	INCW SP	DECW	MOVW SP,A	MOVW A,SP
7	ROLC	CMP A	ADDCA	SUBC	XCH A, T	XOR A	AND A	OR A	MOV @A,T	MOV A,@A	CLRB dir: 2	BBC dir: 2,rel	INCW	DECWIX	MOVW IX,A	MOVW A,IX
r	RORC A	CMPW A	ADDCW A	SUBCW	XCHW A, T	XORW A	ANDW A	ORW A	MOVW @A,T	MOVW A,@A	CLRB dir: 3	BBC dir: 3,rel	INCW	DECW EP	MOVW EP,A	MOVW A,EP
4	MOV A,#d8	CMP A,#d8	ADDC A,#d8	SUBC A,#d8		XOR A,#d8	AND A,#d8	OR A,#d8	DAA	DAS	CLRB dir: 4	BBC dir: 4,rel	MOVW A,ext	MOVW ext,A	MOVW A,#d16	XCHW A,PC
5	MOV A,dir	CMP A,dir	ADDC A,dir	SUBC A,dir	MOV dir,A	XOR A,dir	AND A,dir	OR A,dir	MOV dir,#d8	CMP dir,#d8	CLRB dir: 5	BBC dir: 5,rel	MOVW A,dir	MOVW dir,A	MOVW SP;#d16	XCHW A,SP
ဖ	MOV A,@IX +d	CMP A, @IX +d	ADDC A,@IX +d	SUBC A,@IX +d	MOV @IX +d,A	XOR A,@IX +d	AND A,@IX +d	OR A,@IX +d	MOV @IX+d,#d8	CMP @IX +d,#d8	CLRB dir: 6	BBC dir: 6,rel	MOVW A,@IX +d	MOW @IX+d,A	MOVW IX,#d16	XCHW A,IX
7	MOV A,@EP	CMP A,@EP	ADDC A,@EP	SUBC A,@EP	MOV @EP,A	XOR A,@EP	AND A,@EP	OR A,@EP	MOV @ EP;#d8	CMP @EP;#d8	CLRB dir: 7	BBC dir: 7,rel	MOVW A,@EP	MOVW @EP,A	MOVW EP;#d16	XCHW A,EP
ω	MOV A,R0	CMP A,R0	ADDC A,R0	SUBC A,R0	MOV R0,A	XOR A,R0	AND A,R0	OR A,R0	MOV R0,#d8	CMP R0,#d8	SETB dir: 0	BBS dir: 0,rel	INC R0	DEC R0	CALLV #0	BNC
6	MOV A,R1	CMP A,R1	ADDC A,R1	SUBC A,R1	MOV R1,A	XOR A,R1	AND A,R1	OR A,R1	MOV R1,#d8	CMP R1,#d8	SETB dir: 1	BBS dir: 1,rel	INC R1	DEC R1	CALLV #1	BC
A	MOV A,R2	CMP A,R2	ADDC A,R2	SUBC A,R2	MOV R2,A	XOR A,R2	AND A,R2	OR A,R2	MOV R2,#d8	CMP R2,#d8	SETB dir: 2	BBS dir: 2,rel	INC R2	DEC R2	CALLV #2	BP rel
۵	MOV A,R3	CMP A,R3	ADDC A,R3	SUBC A,R3	MOV R3,A	XOR A,R3	AND A,R3	OR A,R3	MOV R3,#d8	CMP R3,#d8	SETB dir: 3	BBS dir: 3,rel	INC R3	DEC R3	CALLV #3	BN
ပ	MOV A,R4	CMP A,R4	ADDC A,R4	SUBC A,R4	MOV R4,A	XOR A,R4	AND A,R4	OR A,R4	MOV R4,#d8	CMP R4,#d8	SETB dir: 4	BBS dir: 4,rel	INC R4	DEC R4	CALLV #4	BNZ rel
D	MOV A,R5	CMP A,R5	ADDC A,R5	SUBC A,R5	MOV R5,A	XOR A,R5	AND A,R5	OR A,R5	MOV R5,#d8	CMP R5,#d8	SETB dir: 5	BBS dir: 5,rel	INC R5	DEC R5	CALLV #5	BZ rel
ш	MOV A,R6	CMP A,R6	ADDC A,R6	SUBC A,R6	MOV R6,A	XOR A,R6	AND A,R6	OR A,R6	MOV R6,#d8	CMP R6,#d8	SETB dir: 6	BBS dir: 6,rel	INC R6	DEC R6	CALLV #6	BGE rel
Ľ	MOV A,R7	CMP A,R7	ADDC A,R7	SUBC A,R7	MOV R7,A	XOR A,R7	AND A,R7	OR A,R7	MOV R7,#d8	CMP R7,#d8	SETB dir: 7	BBS dir: 7,rel	INC R7	DEC R7	CALLV #7	BLT rel

■ MASK OPTIONS

	Part number	MB89821/823	MB89P825	MB89PV820
No.	Specifying procedure	Specify when ordering masking	Set with EPROM programmer	Setting not possible (Fixed)
1	Pull-up resistors P20 to P25, P30 to P33, P40 to P45	Selectable by pin	Can be set per pin	Without pull-up resistor
2	Power-on reset With power-on reset Without power-on reset	Selectable	Can be set	With power-on reset
3	Oscillation stabilization time selection $(F_c = 5 \text{ MHz})^{11}$ Approx. 2 ¹⁷ /F _c (Approx. 26.2 ms) Approx. 2 ¹³ /F _c (Approx. 1.64 ms)	Selectable	Can be set	Oscillation stabilization time Approx. 2 ¹⁷ /Fc (Approx. 26.2 ms)
4	Reset pin output With reset output Without reset output	Selectable	Can be set	With reset output
5	Segment output switching 50 segments: No port selection 49 segments: Selection of P17 48 segments: Selection of P17 to P16 46 segments: Selection of P17 to P14 42 segments: Selection of P17 to P10 34 segments: Selection of P17 to P10 and P07 to P00	Selectable*2	Can be set⁺³	Can be set [∗] 3

*1: The oscillation settling time is generated by dividing the oscillation clock frequency. Since the oscillation period is not stable immediately after oscillation has been started, therefore, the oscillation settling time in the above list should be regarded as a reference.

*2: Port selection must be same setting of the segment output selection register of LCD controller.

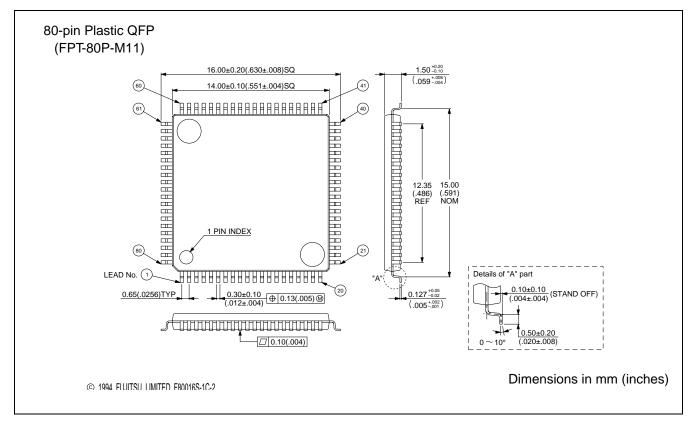
*3: Note that, when ports are set, the input voltage value for the port pins are different from those for mask ROM products.

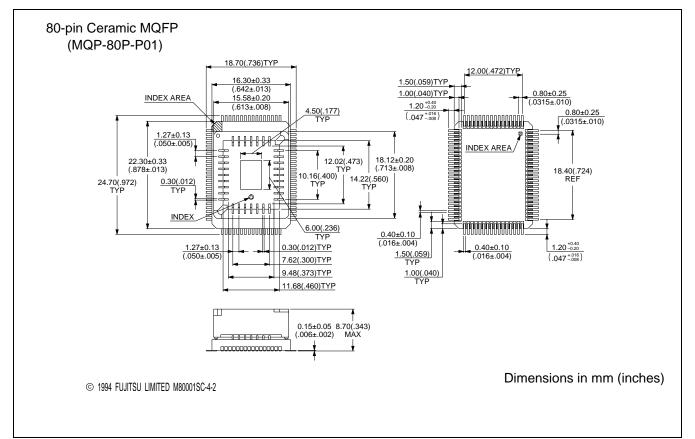
Ports are set by the register setting of the segment output selection register of LCD controller.

ORDERING INFORMATION

Part number	Package	Remarks
MB89821PFM MB89823PFM MB89P825PFM	80-pin Plastic QFP (FPT-80P-M11)	
MB89PV820CF	80-pin Ceramic MQFP (MQP-80C-P01)	

■ PACKAGE DIMENSIONS





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